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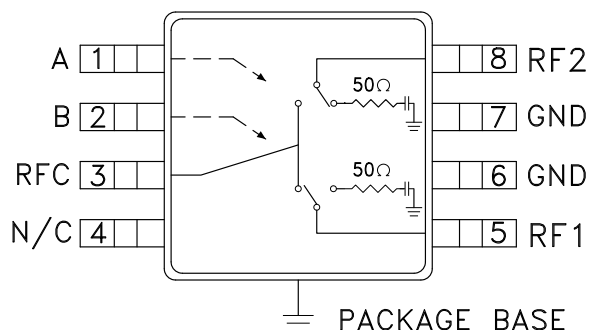
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Typical Applications

The HMC435MS8G(E) is ideal for:

- Basestations & Repeaters
- Cellular/3G and WiMAX/4G
- Infrastructure and Access Points
- CATV/CMTS
- Test Instrumentation

Functional Diagram



Features

- High Isolation: 60 dB @ 1 GHz
50 dB @ 2 GHz
- Positive Control: 0/+5V
- Input IP3: 51 dBm
- Non-Reflective Design
- Ultra Small MSOP-86 Package: 14.8 mm²

General Description

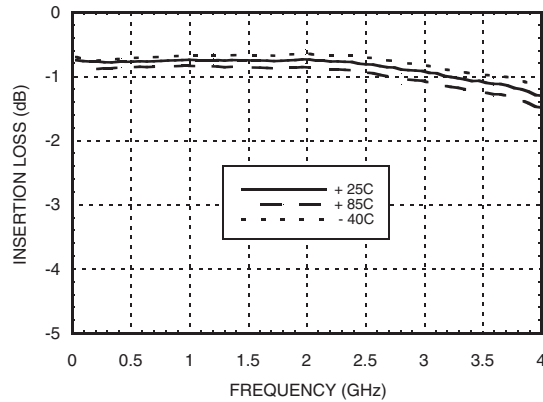
The HMC435MS8G(E) is a non-reflective DC to 4 GHz GaAs MESFET SPDT switch in a low cost 8 lead MSOP8G surface mount package with exposed ground paddle. The switch is ideal for cellular/3G and WiMAX/4G applications yielding up to 60 dB isolation, low 0.8 dB insertion loss and +50 dBm input IP3. Power handling is excellent up through the 3.8 GHz WiMAX band with the switch offering a P1dB compression of +31 dBm. On-chip circuitry allows positive voltage control of 0/+5 Volts at very low DC currents.

Electrical Specifications, $T_A = +25^\circ \text{C}$, $V_{ctl} = 0/+5 \text{ Vdc}$, 50 Ohm System

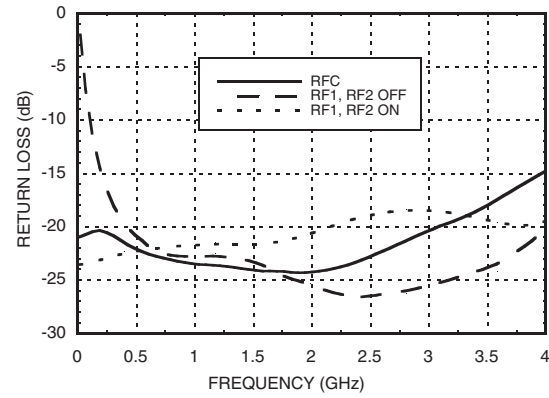
Parameter	Frequency	Min.	Typ.	Max.	Units
Insertion Loss	DC - 2.5 GHz		0.8	1.0	dB
	DC - 3.6 GHz		1.2	1.5	dB
	DC - 4.0 GHz		1.5	1.8	dB
Isolation (RFC to RF1/RF2)	DC - 1.0 GHz	56	60		dB
	DC - 2.0 GHz	46	50		dB
	DC - 2.5 GHz	43	47		dB
	DC - 3.6 GHz	37	41		dB
	DC - 4.0 GHz	30	35		dB
Return Loss (On State)	DC - 2.5 GHz	15	20		dB
	DC - 3.6 GHz	13	17		dB
	DC - 4.0 GHz	11	15		dB
Return Loss (Off State)	0.5 - 4.0 GHz	16	21		dB
Input Power for 1 dB Compression	0.5 - 4.0 GHz	27	31		dBm
Input Third Order Intercept (Two-Tone Input Power = +7 dBm Each Tone)	0.5 - 1.0 GHz	48	51		dBm
	0.5 - 2.5 GHz	45	48		dBm
	0.5 - 4.0 GHz	41	45		dBm
Switching Speed	DC - 4.0 GHz				
tRISE, tFALL (10/90% RF)			40		ns
tON, tOFF (50% CTL to 10/90% RF)			60		ns

SPDT NON-REFLECTIVE SWITCH, DC - 4 GHz

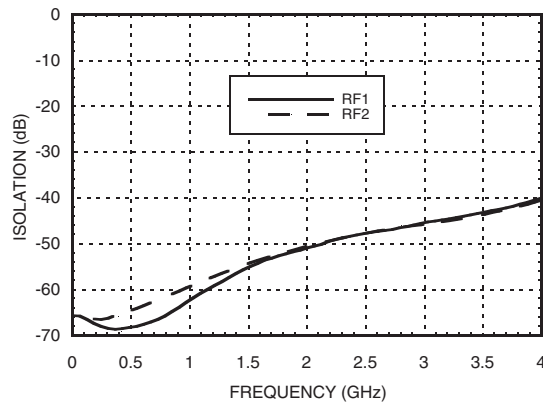
Insertion Loss



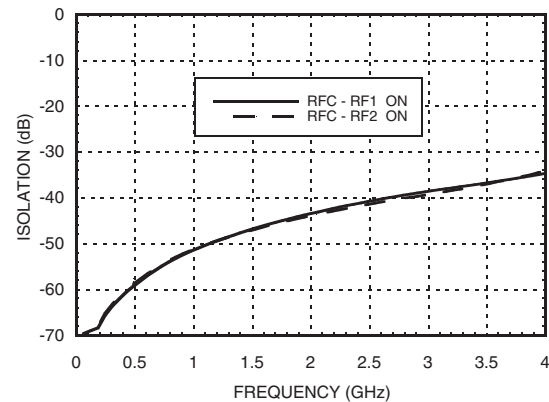
Return Loss



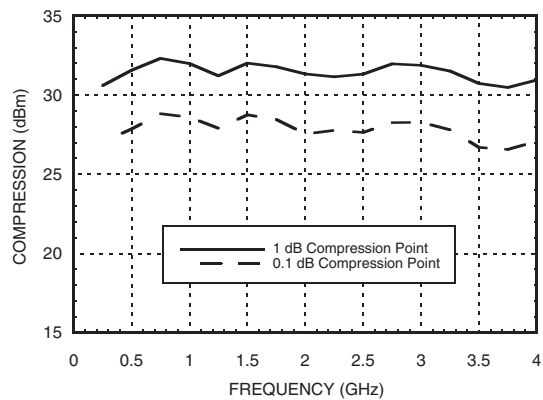
**Isolation Between
Ports RFC and RF1 / RF2**



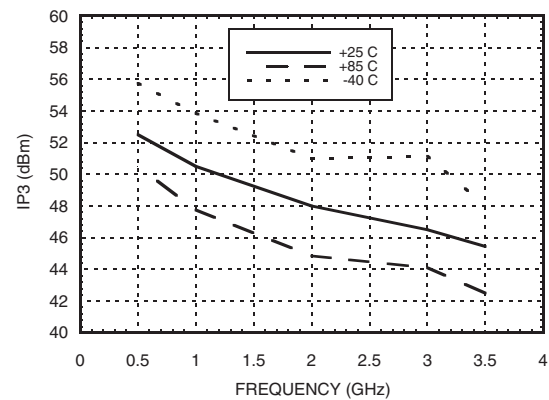
Isolation Between Ports RF1 and RF2



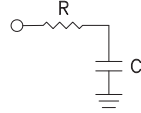
0.1 and 1 dB Input Compression Point



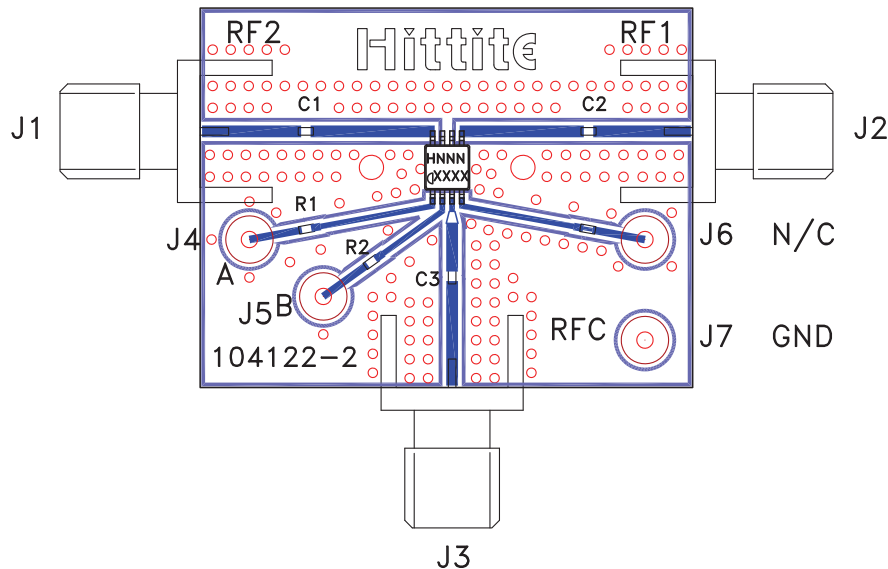
Input Third Order Intercept Point



Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	A	See truth and control voltage tables.	
2	B	See truth and control voltage tables.	
3, 5, 8	RFC, RF1, RF2	These pins are DC coupled and matched to 50 Ohms. Blocking capacitors are required.	
4	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
6, 7	GND	Package bottom has exposed metal paddle that must be connected to PCB RF ground as well.	

Evaluation PCB



List of Materials for Evaluation PCB 105143 ^[1]

Item	Description
J1 - J3	PCB Mount SMA RF Connector
J4 - J7	DC Pin
C1 - C3	100 pF Capacitor, 0402 Pkg.
R1 - R2	100 Ohm Resistor, 0402 Pkg.
U1	HMC435MS8G(E) SPDT Switch
PCB ^[2]	104122 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350

The circuit board used in the application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 Ohm impedance and the package ground leads and backside ground slug should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.

Note: Pin J6 is unused and need not be connected.

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:
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Order On-line at www.hittite.com